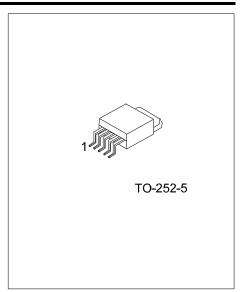
LR5966 CMOS IC

# **5A LOW DROPOUT LINEAR** REGULATOR

#### **DESCRIPTION**

The UTC LR5966 belonged to low guiescent current(60µA typ.), low dropout, linear regulators operating from 2.25V to 6V input and are guaranteed to deliver 5A. Wide range of preset output voltage options are available. Built-in low on-resistance transistor provides low dropout voltage and large output current. The UTC LR5966 are designed and optimized for battery-powered systems to work with low noise.

The UTC LR5966 consume less than 0.01µA in shutdown mode. Other features include ultra low dropout voltage, current limiting protection, thermal shutdown protection and high ripple rejection ratio.



#### **FEATURES**

- \* 5A Guaranteed Output Current
- \* 0.01µA Shutdown Current
- \* Low Temperature Coefficient
- \* Current Limiting Protection
- \* Thermal Shutdown Protection
- \* Excellent Line/Load Transient

## **ORDERING INFORMATION**

Ordering Number		Daakaga	Pin Assignment					Dooking	
Lead Free Halogen Free		Package	1	2	3	4	5	Packing	
LR5966L-xx-TN5-R	LR5966L-xx-TN5-R LR5966G-xx-TN5-R		S	1	G	0	Α	Tape Reel	
LR5966L-xx-TN5-T	-xx-TN5-T LR5966G-xx-TN5-T		S	1	G	0	Α	Tube	

Note: Pin Assignment: I:V<sub>IN</sub> O:V<sub>OUT</sub> G:GND S: SHDN A: SET

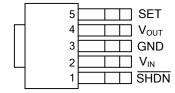


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## **MARKING INFORMATION**

PACKAGE	VOLTAGE CODE	MARKING					
TO-252-5	33 :3.3V	Pin Code  Voltage Code  1 2 3 4 5					

## PIN CONFIGURATION



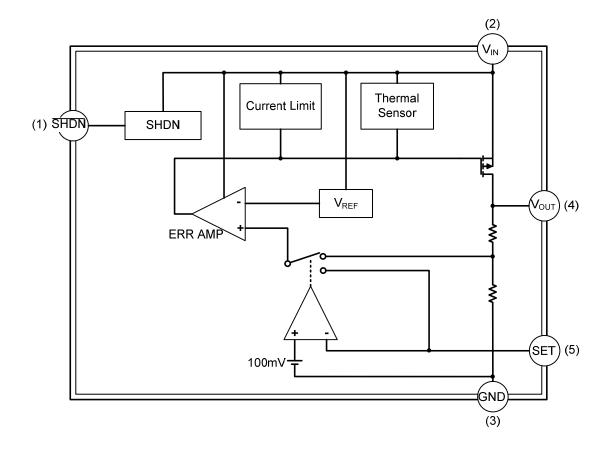
### ■ PIN DESCRIPTION

PIN NO	PIN NAME	DESCRIPTION
1	SHDN	Active-Low Shutdown Input. A logic low at SHDN reduces supply current to 0.01µA.
		Connect SHDN to V <sub>IN</sub> for normal operation.
2	$V_{IN}$	Power Input Voltage. Supply voltage can range from 2.25V to 6V.
3	GND	Ground
4	$V_{OUT}$	Output Voltage
5	SET	When this pin is connected to ground, turns to fixed output voltage operation.  When this pin is connected to an external resistor divider, turns to adjustable output voltage mode operation.



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## **BLOCK DIAGRAM**



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## ■ ABSOLUTE MAXIMUM RATING (T<sub>A</sub>=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	$V_{IN}$	7	V
Power Dissipation	$P_{D}$	1250	mW
Junction Temperature	$T_J$	+125	°C
Operation Temperature	T <sub>OPR</sub>	-40 ~ +125	°C
Storage Temperature	T <sub>STG</sub>	-65 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### **■ THERMAL DATA**

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	$\theta_{JA}$	64	°C/W
Junction to Case	$\theta_{JC}$	4	°C/W

## ■ **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub>= 25°C, unless otherwise specified)

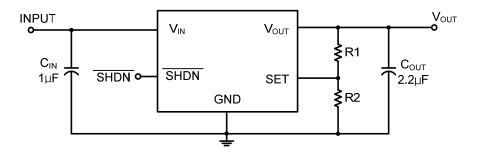
 $V_{IN}$  =  $V_{OUT}$  + 1V or  $V_{IN}$  =2.25V whichever is greater,  $C_{IN}$  =1 $\mu$ F,  $C_{OUT}$  =2.2 $\mu$ F(Ceramic)

PARAMETER	SYMBOL	TEST CONDITIONS			MIN	TYP	MAX	UNIT	
Input Voltage	V <sub>IN</sub>				2.25		6	V	
Output Voltage Accuracy	V	T <sub>A</sub> =25°C , I <sub>OUT</sub> = 1mA ~5A			-2		2	%	
Output Voltage Accuracy	$V_{OUT}$	T <sub>A</sub> =0~85°C, I <sub>OUT</sub> = 1mA~5A			-3		3		
Maximum Output Current	I <sub>OUT</sub>					5		Α	
Short-Circuit Current Limit	I <sub>LIMIT</sub>	V <sub>OUT</sub> >1.2V				7.5		Α	
Reference Current	$V_{REF}$	Measured on SET, V <sub>IN</sub> =2.8V, I <sub>OUT</sub> =10mA			0.784	0.8	0.816	V	
Crawad Dia Correct	1	I <sub>OUT</sub> = 0mA				60			
Ground Pin Current	$I_{GND}$	I <sub>OUT</sub> = 1mA to	5A			90		μA	
			1.5V<=V <sub>O</sub>	<sub>UT</sub> <=1.8V			1800		
Dropout Voltage (Note)	V <sub>D</sub>	I <sub>OUT</sub> =5A	1.8V <v<sub>OUT&lt;2.5V</v<sub>				1000	mV	
		2.5<=V <sub>OUT</sub>					650		
Line Regulation	$\frac{\Delta V_{OUT}}{\Delta V_{IN} \times V_{OUT}}$	V <sub>IN</sub> =V <sub>OUT</sub> +V <sub>D</sub> ~6V				0.08	0.18	%/V	
Load Regulation	$\Delta V_{OUT}$	V <sub>IN</sub> =V <sub>OUT</sub> +1V, I <sub>OUT</sub> =10mA~5A				0.25	1	%	
Output Voltage Noise	eN	f=10Hz to10	OkHz, Cou	<sub>ιτ</sub> =2.2μF		30		$\mu V_{RMS}$	
Shutdown Supply Current	I <sub>OFF</sub>	SHDN =GND				0.01	5	μA	
Decree O and Defection	PSRR	I <sub>OUT</sub> =100mA		f=100Hz		60		dB	
Power Supply Rejection		C <sub>OUT</sub> =10µF		f=1kHz		45			
Ol. ( Lee The sector)	V <sub>IH</sub>				1.6			V	
Shutdown Threshold	V <sub>IL</sub>						0.6	V	
Thermal Shutdown Temperature	T <sub>SHDN</sub>					160		°C	
Thermal Shutdown Hysteresis	DT <sub>SHDN</sub>					50			

Note: The dropout voltage is defined as  $V_{IN}$  - $V_{OUT}$ , which is measured when  $V_{OUT}$  is  $V_{OUT(NORMAL)}$  - 100mV.



### **■ TYPICAL APPLICATION CIRCUIT**



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